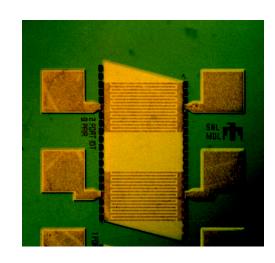
Micro-Nano Sensors & Actuators for Use in Extreme Environments

Bruce Tuttle, Geoff Brennecka, Chris Apblett, Joe Henfling, Chad Parish and Paul Galambos Sandia National Laboratories John Ekerdt University of Texas at Austin, Paul Nealey, University of Wisconsin Jacob Jones, University of Florida



Multilayer Piezoelectric Fuel Injector

NINE Workshop Marriott Hotel Albuquerque, NM July 29, 2008



Bulk Acoustic Surface Wave Piezoelectric Sensor

Sandia National Laboratories

Extreme Environment Sensors and Actuators Needed For Many Applications



Unattended Ground Sensors



Down Hole Well Drilling



Process Control,
Integrated Electronics
And
Bio – Medical

Nano-Micro Materials Advances Required to Improve Sensor Technology



Example: Pressure Measurement Improvements Needed for Down Hole Well Drilling

There are Many Other Sensor Applications that NINE Teams Can Impact

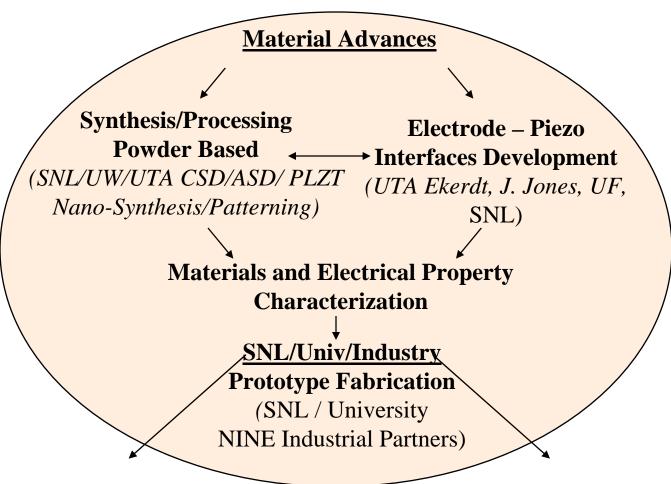
Improved Sensors Will Save Millions of Dollars for U.S. Down Hole Well Drilling Industry

Improvements Needed

- Reliably measure small changes in dynamic pressure
 - High resolution
 - Smaller packages
 - Higher Temperature (HT) Performance
- Highly Stable Pressure Sensors
 - Minimal drift at high temperatures > 150°C
 - Replace strain gauges

Solution: Form NINE Team of Industry, SNL, UTA, Univ of Wisconsin, U of Florida with Materials, Commercial Innovations and Prototype device capabilities to develop microstructure and element patterning at the nanoscale level that will enable next generation HT piezoelectric sensors with improved sensitivity and stability (drift)

NINE Micro-Nano Sensor Project Will Enable New Well Drill Capabilities Via Materials Advances



Project Manager: J. Voigt SNL DM

Principal Investigators:

G. Brennecka,

B. Tuttle SNL Staff

Team Members:

J. Ekerdt (UTA)

P. Nealey (UW)

J. Jones (UF)

J.Henfling, P.Galambos

B.Hernandez, D.Moore

C. Parish (SNL)
Industry

Nanomaterials/Analyses/ Patterning

P. Nealey, UW

J. Ekerdt, UTA

J. Jones, UF; C. Parish SNL

Prototype Fabrication

G. Brennecka, B. Tuttle

P. Galambos (Adv. MEMS)

J. Henfling (Geo Therm Res)



Sandia Has Down Hole Expertise Via Energy Research and Systems Analysis

- Down Hole Life Time Studies SOI microelectronics, Capacitors, Pressure Sensors
- TPS Dewared Memory Tool
- Fluid Sampler
- DWD POC and HT Drilling Tool
- Dewarless PTL monitoring tools (USGS and NETL)
- 300 °C Analog PT Well Monitoring Tools

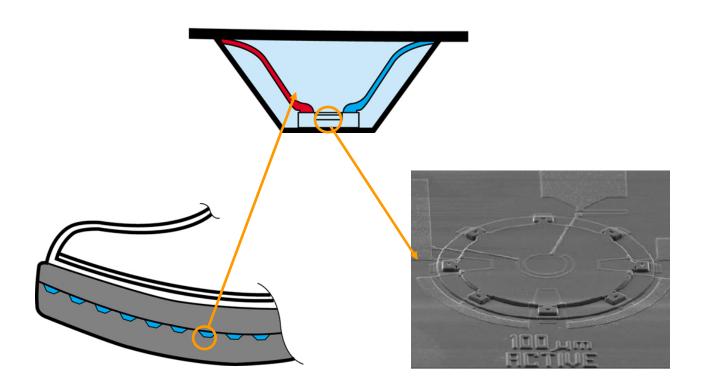


200°C SNL Tests of SOI Microelectronics



Microelectronic Sensors Developed to Monitor Soldiers for DARPA

 Advanced MEMS Pressure Sensor Design and Fabrication Capability (Paul Galambos)



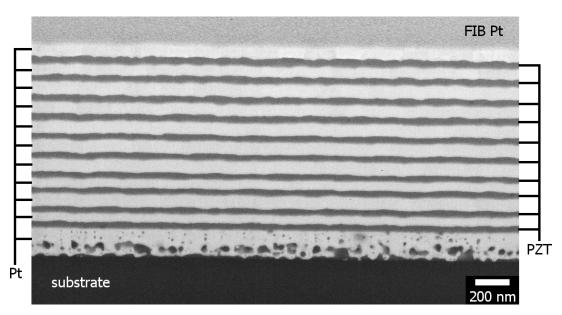
Provides Load History – Monitors soldier activities (DARPA) Have also Invented a MEMS array Normal Stress Sensor for Monitoring Penetrator Loading



System Needs / Initial Prototypes Drives Materials Advances

- MEMs Devices / PZT based piezoelectrics
 - FPW Devices, Motion Detectors
 - Nanopowder 3D
 Actuator Elements
 - Bio-Lab on a Chip Applications
 - Ultrathin Film PLZT
 Multilayer Capacitors
- Metal Contacts
- Non Pb Containing Materials Development

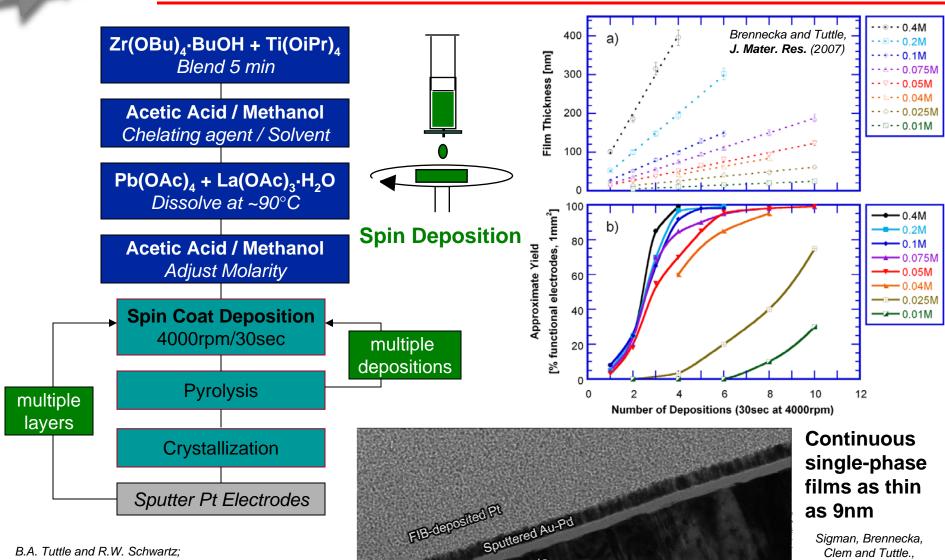
SNL Has Highest Known Large Operating Temperature Range Areal Capacitor Technology



10 layer, 50 nm thick PLZT Layers 1 µF/mm²



SNL IMO-based Solution Route



Pt electrode

B.A. Tuttle and R.W. Schwartz; MRS Bulletin (1996)

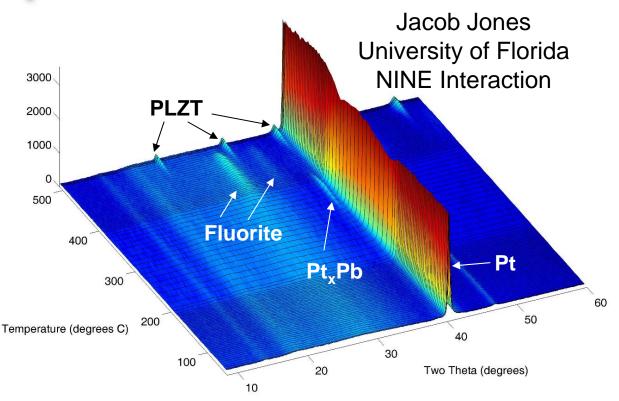
G. Yi and M. Sayer: J. Appl. Phys. (1988) as 9nm

Sigman, Brennecka, Clem and Tuttle.. J. Am. Ceram. Soc. (2008)

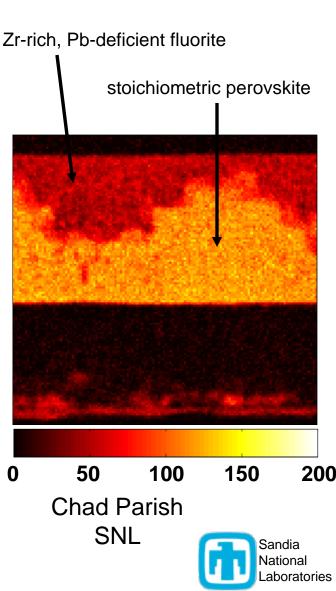


25 nm

in-situ & ex-situ Studies of Phase/Interface Development

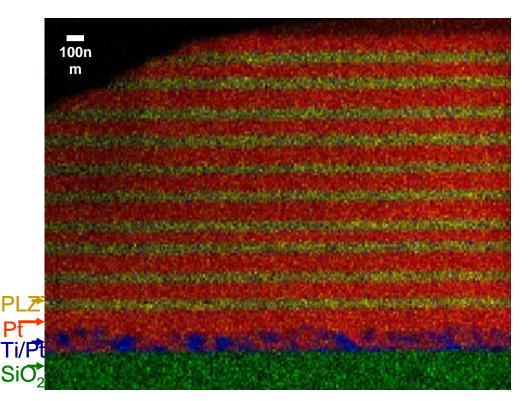


- in-situ hot-stage XRD reveals presence and effects of transient phases
- ex-situ quantitative chemical spectrum imaging in TEM relates chemistry to phase/interface information from XRD with high spatial resolution



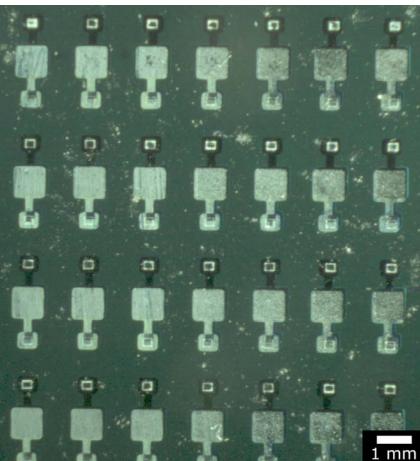
Ten Active Layer PLZT MLC Device, ~50nm

TEM Multivariate Spectral Image of Multilayer Cross-Section



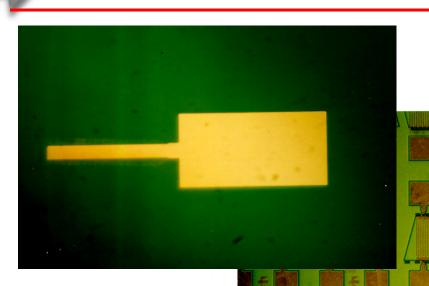
Enhanced Sensitivity per unit volume with thin multilayers

Batch Process Photolithographically Defined PLZT Ultrathin Film Devices

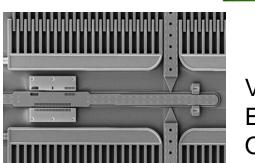




SNL Has Wide Ranging Efforts in **MEMS Devices**



PZT – MEMs Piezo Cantilever Beam – Energy Harvesting



Bulk Acoustic Wave Modulators

Vapor phase lubricants Extend slide life by 5 orders Of Magnitude, D. Tanner Alternate Hard Materials
ALD To Increase lifetime
SiC T. Friedman



150 µm



SNL Chem-Prep Process (Patent) Consists of:

- 1) Synthesis of Pb Acetate
- 2) Dissolution of: A) Pb Acetate in Glacial Acetic Acid and
 - B) Nb, Zr and Ti n-butoxides in Acetic Acid
- 3) Blending of the two solutions
- 4) Precipitation using Oxalic Acid / n-Propanol Solutions

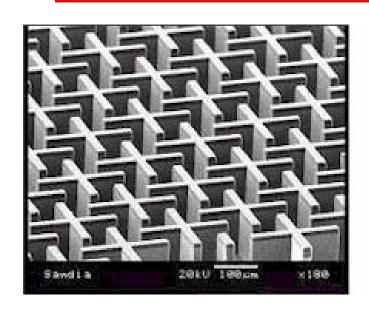


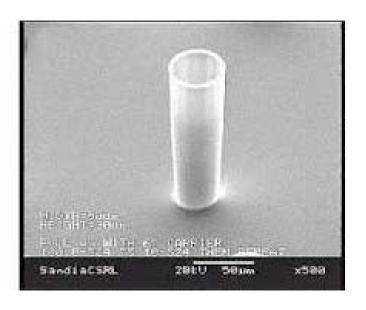
Metal Solution Precipitated With Oxalic Acid / n-Proponal

More than 100 batches of 1500 grams fabricated, ± 0.02 Mol% Ti, $\pm 0.5\%$ Remanent Polarization; $\pm 0.1\%$ Density



PZT Nanopowders to Enable Bosch Etched Micromold Patterns in Silicon for Sensors





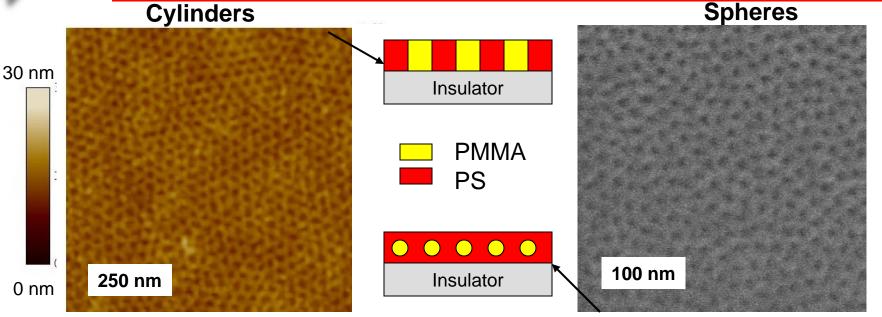
Micromolding process: size of piezoelectric elements controlled by lithography that can achieve dimensions unachievable using dicing technology.

- 1) A glass mold of the pattern is prepared using standard lithographic and dry etching techniques.
- 2) Mold is filled with powder, pressed in standard press and sintered.
- 3) Excellent materials properties observed in large scale devices Technical Challenge:

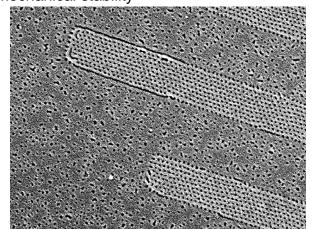
Nanocrystalline, mono-domain grain materials with ultraclean Grain boundaries.



Bilevel Patterning via Graphoepitaxy of Diblock Copolymers (UTA – NINE, J.Ekerdt)



AFM image of cylindrical P(S-b-MMA) template on silicon dioxide after sputtered with gold for mechanical stability



SEM image of spherical P(S-b-MMA) template

PMMA cylinders

70% styrene, 30% methyl methacrylate 20 nm diameter pores, ~6×10¹⁰ cm⁻²

PMMA spheres in monolayer

83% styrene, 17% methyl methacrylate 12 nm diameter pores, ~1.2×10¹¹ cm⁻²

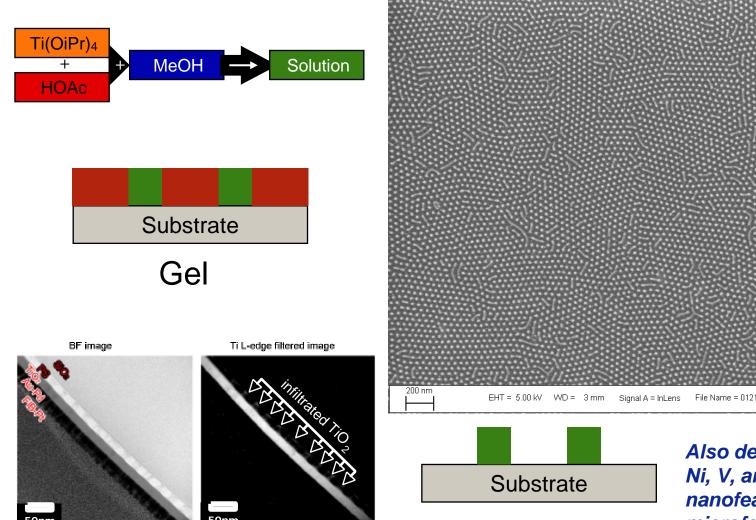
➤ If hexagonal, 31 nm center-to-center



Soft Nanomaterials Development Leads to Patterned Hard Electronic Oxide Nanomaterials

Remove PS

UTA, SNL, UW NINE Collaboration (Paul Nealey UW and Erik Spoerke SNL Soft Matls)



TiO₂ solution infiltrates 20nm columnar features in nanopatterned PS (also shown for HfO₂)

Also demonstrated with Ni, V, and Mn oxides in nanofeatures; PZT in microfeatures

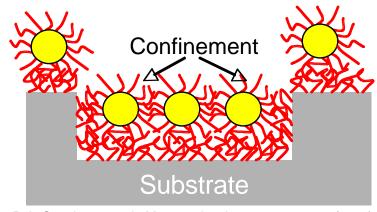
> Sandia National

Laboratories

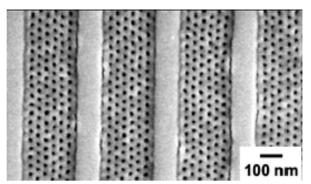
microreatures

Graphoepitaxy Demonstrated For SiO₂

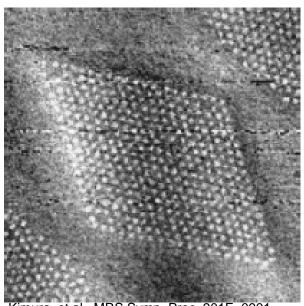
- Geometric confinement can lead to 'crystalline' single-domain state
- Demonstrated for Si / SiO₂ with cylindrical and spherical diblocks
- Pre-defined pixel location



R.A. Segalman, et al., Macromolecules, 36 4498-4506 (2003)



C. T. Black, et al., IEEE Trans. Nanotechnology 3 (5) 412-415 (2004)



Kimura, et al., MRS Symp. Proc. 901E, 0901-

Ra05-05-Rb05-05.1 (2006)

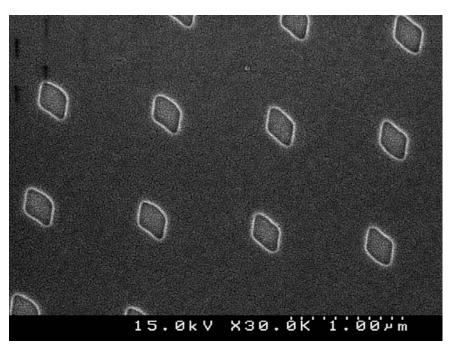


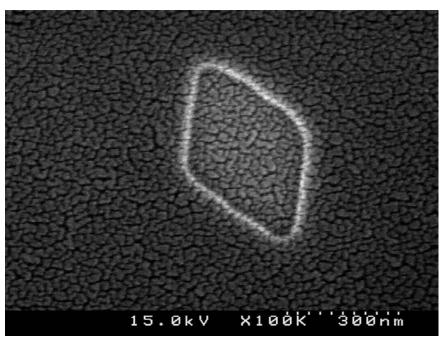
NINE Collaborations Result in Game Changing Technological Advances

- Discussions with (SNL Experts) indicate US industry will Save Millions of Dollars with High Stability, Higher Sensitivity Extreme Environment Sensors
- Wide Range of Applications: Integrated Electronics Monitoring, Process Control, Well Drilling, etc.
- Control of Grain Size of Complex Oxide Materials and Grain Boundary Interfaces on the Nanoscale Essential for Extreme Environment Sensors and Actuators
- Mesh Industry Know How with University Fundamental Nano materials Expertise and SNL Nano-Micro Materials / Device Capabilities Can Result in Substantial Improvements for Extreme Environment Sensors



Transfer etch, SEM results using CINT EBL





~0.3 micron parallelograms, transfer comes from 245 nm template

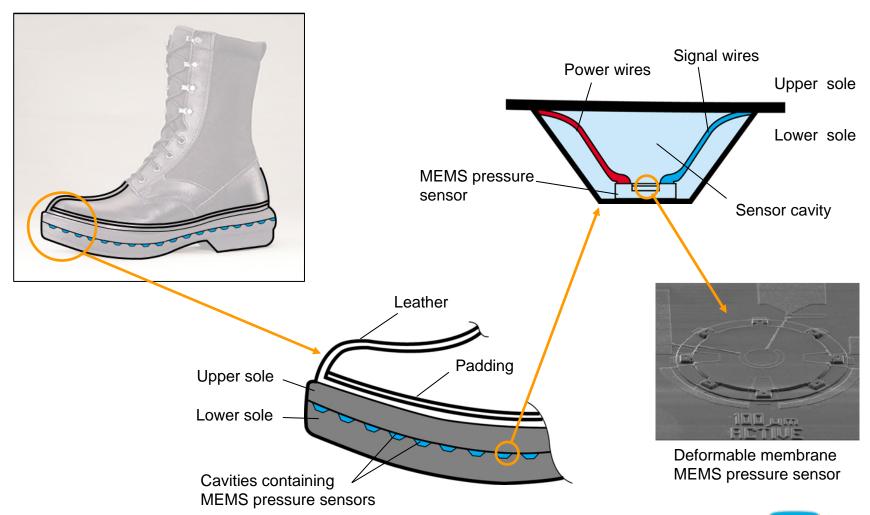


Sandia Developed Tools

- TPS Dewared Memory Tool
- Spectral Gamma Memory Tool
- CTDL Memory Tool
- Fluid Sampler
- Televiewer (Joint with Navy, USGS and Mount Sopris Instrument Co.)
- DWD POC and HT Drilling Tool
- PT Memory Drilling Tools (For Unsen Scientific Drilling Program - Tohoku University)
- Dewarless PT Well Monitoring Tools (For NETL and USGS)
- 300 C Analog PT Well Monitoring Tools



Transducer Packaging (1) ExoBoot: In-sole Pressure Profiler Concept (DARPA)

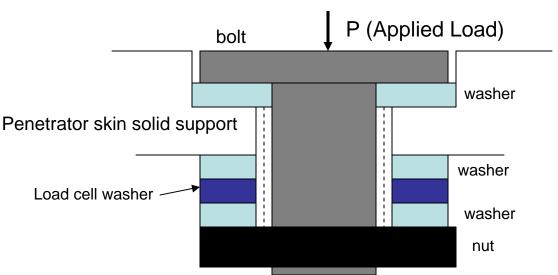


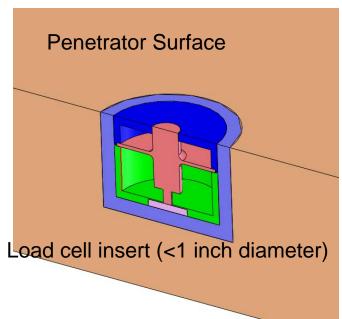


MEMS Normal Stress Sensor for Monitoring Penetrator Loading

Vincent Luk (Department 5431) and Paul Galambos (Department 1769)

Threaded Load Cell Insert in Penetrator Skin.





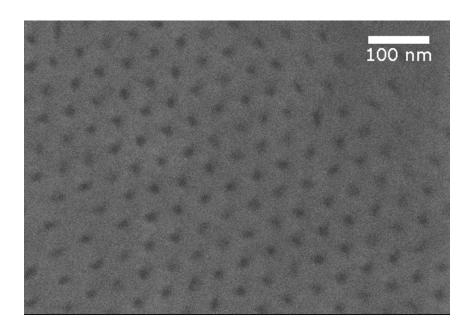
_aboratories

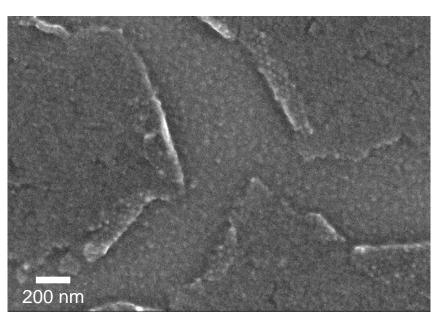
The load cell washer consists of a commercial load cell (COTS version) or MEMS pressure transducer array (high load MEMS version) and is the sensing element of the Penetrator surface load cell insert.

- COTS version bench test design under way test this FY.
- MEMS design of pressure sensor array awaiting results of COTS test.
- MEMS pressure sensor array will provide higher load information in a smaller package than COTS load washer. Also, MEMS array will provide a load distribution providing more information about Penetrator surface load details (e.g. load angle, time history...)

Nanopatterning: TiO₂ deposition

- Very little success since first attempt
- Problems appear to be due to removal of mask layer

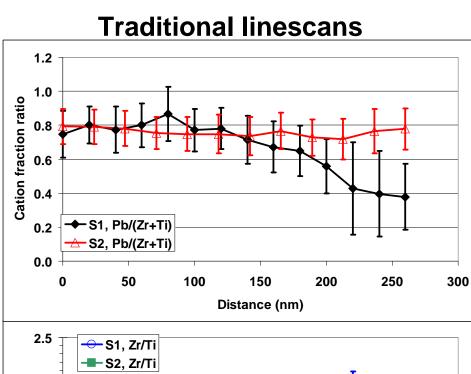


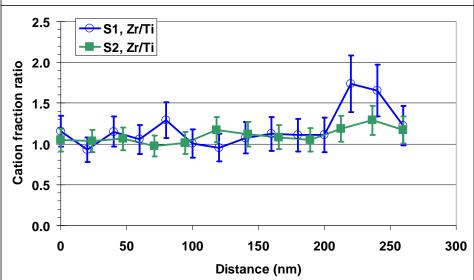


 Repeated exact procedure from first trial with longer 'soak' time before spinning; waiting for SEM

Spectral Image Derived Line Scans: Needed Analytical Tool







Extracted from SIs

